

Antiferromagnets Are Suitable for Dissipationless Nanoelectronics, Contrary to Current Theories

2020-11-18 Young physicist at Mainz University discovers the Hall effect in an antiferromagnet, which – according to current theories – is impossible.

Sometimes combinations of different things produce effects that no one expects, such as when completely new properties appear that the two combined parts do not have on their own. Dr. Libor Šmejkal from Johannes Gutenberg University Mainz (JGU) found such an unexpected property: He combined antiferromagnetic substances with non-magnetic atoms and found that, contrary to the current doctrine, a Hall current occurs – which is not the case with either antiferromagnetic or non-magnetic substances individually.

This could offer completely new potential for nanoelectronics. On the one hand, these material combinations occur very frequently in nature. Therefore, this discovery has the potential to revert the growing demand for rare heavy elements in conventional magneto-electronics and, instead, direct the research and applications towards abundant materials. Furthermore, the Hall current exhibits low dissipation of energy.

This is particularly important in light of the fact that information technology is becoming the largest energy consumer in industries. Since the materials do not have a magnetic field to the outside and are thus magnetically invisible, they can be packed very tightly and allow a high degree of miniaturization of nanoelectronics.

These previously overlooked materials also score in terms of speed since they allow many times greater speed than ferromagnets, so the frequencies could be shifted from the gigahertz range to the terahertz range. In short: The discovery has a special place in the rapidly growing new field of antiferromagnetic magnetoelectronics, which is also referred to as spintronics. Dr. Libor Šmejkal and his colleagues from Mainz University recently published their results in <u>Science Advances</u>.

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Electrons (gray wave packets) in antiferromagnetic (left) and nonmagnetic (middle) crystals move along the applied electric current (right). The combination generates surprisingly transverse Hall motion of the electron.

What is the Hall current?

To understand Šmejkal's research, one must start with the Hall effect named after physicist Professor Edwin Hall. If a voltage is applied to conventional non-magnetic conductors such as copper, the current flows in the direction given by the electric field. However, if an external magnetic field is added, the current bends away from the applied direction. This additional cross component is known as the Hall current.

The described Hall effect has been used for characterizing semiconductors, which shaped modern silicon electronics. Hall's second discovery: The internal magnetization of a ferromagnetic conductor such as iron can also lead to such a cross-current deflection. This made the Hall effect also one of the cornerstones of magnetoelectronics, a broad field that extends from sensor to memory technologies.

The discovery of antiferromagnets, which are much more common in nature than ferromagnets, is attributed to Professor Louis Néel. In these the magnetic moments of the atoms are oriented in opposite directions. The effects observed in ferromagnets therefore cancel each other out – including the Hall current. The antiferromagnets behave towards the outside like the usual non-magnetic conductors and are therefore not applicable for magnetoelectronics.

Unusual effect: Hall current in antiferromagets

Nonmagnetic and antiferromagnetic crystals have been known for decades to be absent of Hall currents. Dr. Libor Šmejkal, however, found a crystal with an intriguing combination of nonmagnetic and antiferromagnetic atoms that produces a strong Hall current. Remarkably, crystals with antiferromagnetic and non-magnetic atoms are not uncommon in nature, but

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rather widespread.

Read the <u>original article</u> on Johannes Gutenberg University of Mainz (JGU).